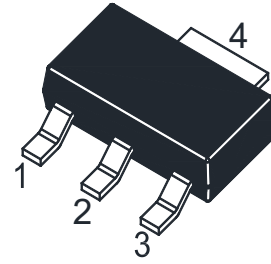


# PZTA42Q-HAF

## NPN Silicon Epitaxial Planar High Voltage Transistor

### Features

- Halogen and Antimony Free(HAF),  
RoHS compliant



1.Base 2.4.Collector 3.Emitter  
SOT-223 Plastic Package

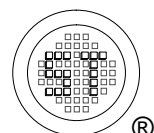
### Absolute Maximum Ratings ( $T_a = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Value	Unit
Collector Base Voltage	$V_{CBO}$	300	V
Collector Emitter Voltage	$V_{CEO}$	300	V
Emitter Base Voltage	$V_{EBO}$	6	V
Collector Current	$I_C$	500	mA
Power Dissipation	$P_{tot}$	1.5	W
Operating Junction Temperature Range	$T_j$	- 55 to + 150	$^\circ\text{C}$
Storage Temperature Range	$T_{stg}$	- 55 to + 150	$^\circ\text{C}$

### Thermal Resistance Ratings

Parameter	Symbol	Max.	Unit
Thermal Resistance from Junction to Ambient <sup>1)</sup>	$R_{\theta JA}$	83.3	$^\circ\text{C}/\text{W}$

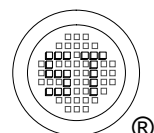
<sup>1)</sup> Device mounted on FR-4 substrate PC board, 2oz copper, with 1-inch square copper plate.



# PZTA42Q-HAF

## Characteristics at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Min.	Max.	Unit
DC Current Gain at $V_{CE} = 10\text{ V}$ , $I_C = 1\text{ mA}$	$h_{FE}$	25	-	-
at $V_{CE} = 10\text{ V}$ , $I_C = 10\text{ mA}$	$h_{FE}$	40	-	-
at $V_{CE} = 10\text{ V}$ , $I_C = 30\text{ mA}$	$h_{FE}$	40	-	-
Collector Base Cutoff Current at $V_{CB} = 200\text{ V}$	$I_{CBO}$	-	100	nA
Emitter Base Cutoff Current at $V_{EB} = 6\text{ V}$	$I_{EBO}$	-	100	nA
Collector Emitter Breakdown Voltage at $I_C = 1\text{ mA}$	$V_{(BR)CEO}$	300	-	V
Collector Base Breakdown Voltage at $I_C = 100\text{ }\mu\text{A}$	$V_{(BR)CBO}$	300	-	V
Emitter Base Breakdown Voltage at $I_E = 100\text{ }\mu\text{A}$	$V_{(BR)EBO}$	6	-	V
Collector Emitter Saturation Voltage at $I_C = 20\text{ mA}$ , $I_B = 2\text{ mA}$	$V_{CE(sat)}$	-	500	mV
Base Emitter Saturation Voltage at $I_C = 20\text{ mA}$ , $I_B = 2\text{ mA}$	$V_{BE(sat)}$	-	900	mV
Current Gain Bandwidth Product at $V_{CE} = 20\text{ V}$ , $I_C = 10\text{ mA}$ , $f = 100\text{ MHz}$	$f_T$	50	-	MHz
Collector Output Capacitance at $V_{CB} = 20\text{ V}$ , $I_E = 0$ , $f = 1\text{ MHz}$	$C_{ob}$	-	3	pF



# PZTA42Q-HAF

## Electrical Characteristics Curves

Fig. 1 Output Characteristics Curve

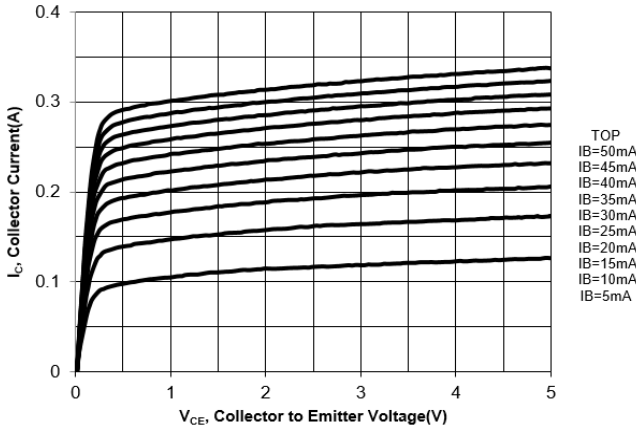


Fig. 2 Collector Current vs.  $V_{BE}$

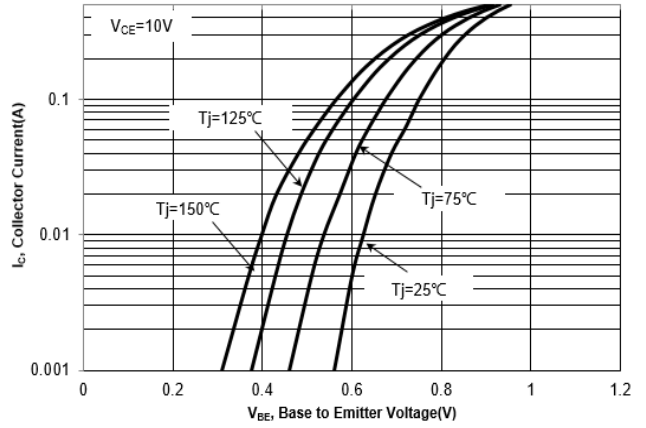


Fig. 3 DC Current Gain vs. Collector Current

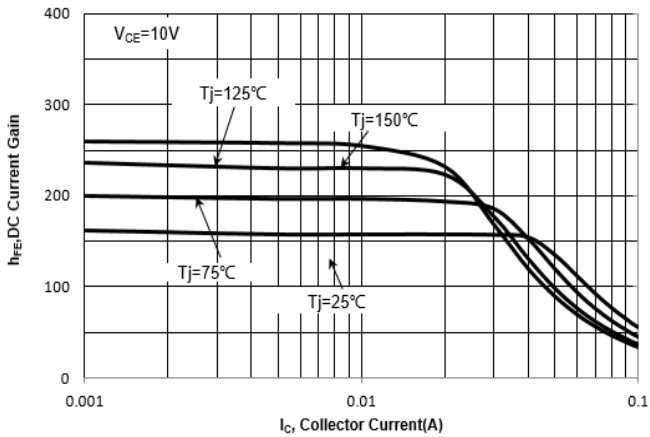
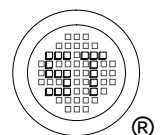
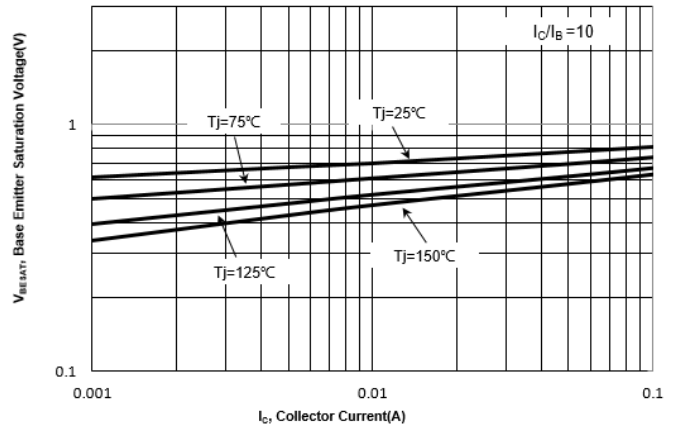


Fig. 4  $V_{BE(sat)}$  vs. Collector Current



# PZTA42Q-HAF

## Electrical Characteristics Curves

Fig. 5  $V_{CE(sat)}$  vs. Collector Current

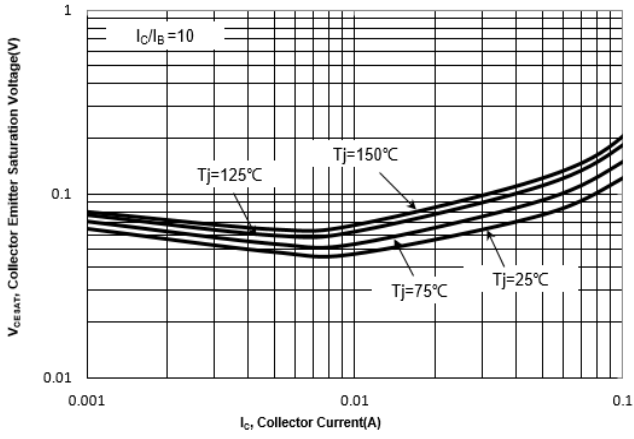


Fig. 6 Output Capacitance

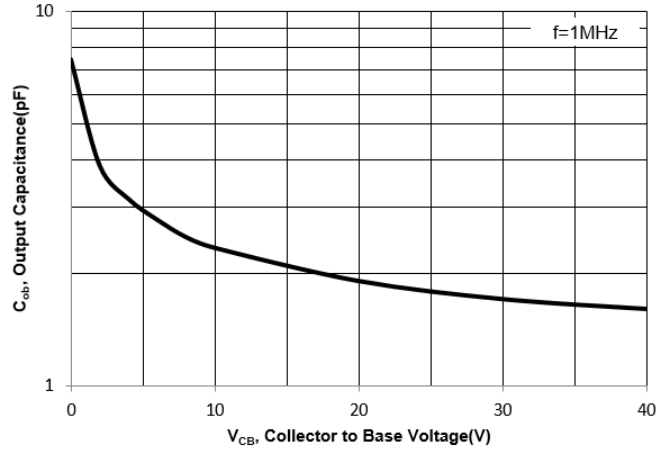
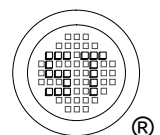
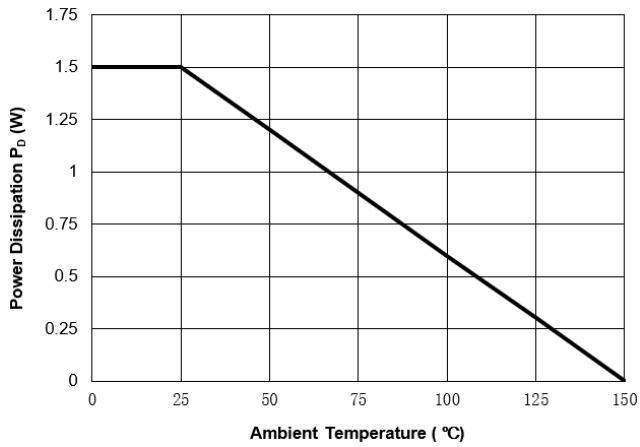


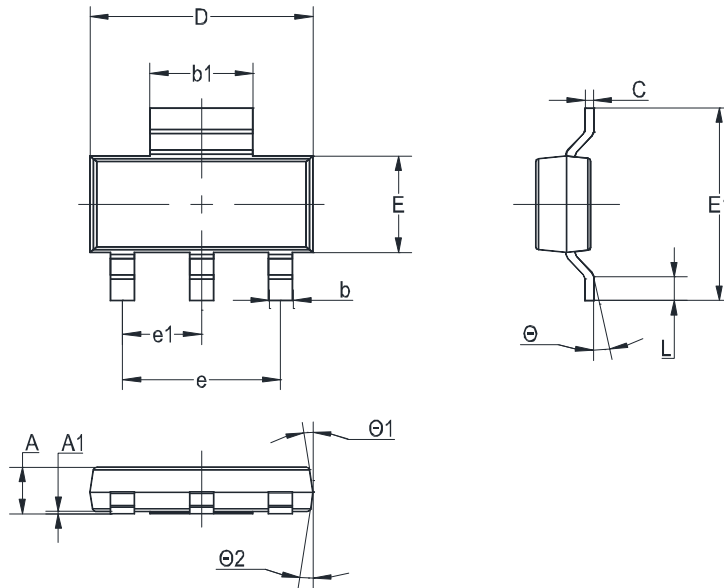
Fig. 7 Power Derating Curve



# PZTA42Q-HAF

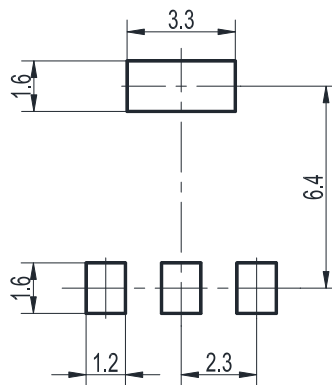
## Package Outline (Dimensions in mm)

SOT-223



Unit	A	A1	b	b1	C	D	E	E1	e	e1	L	Θ	Θ1	Θ2
mm	1.8	0.1	0.8	3.1	0.32	6.7	3.7	7.3	4.6	2.3	1.1	10°	7°	7°
	1.5	MAX	0.6	2.9	0.22	6.3	3.3	6.7	TYP	TYP	0.7	0°	0°	0°

## Recommended Soldering Footprint



## Packing information

Package	Tape Width (mm)	Pitch		Reel Size		Per Reel Packing Quantity
		mm	inch	mm	inch	
SOT-223	12	8 ± 0.1	0.315 ± 0.004	330	13	3,000

## Marking information

" PZTA42Q " = Part No.

" \*\*\*\*\* " = Date Code Marking

Font type: Arial

